

FRED

HFB50HI20

Ultrafast, Soft Recovery Diode

Features

- Reduced RFI and EMI
- Reduced Snubbing
- Extensive Characterization of Recovery Parameters
- Hermetic

| |
|-------------------|
| $V_R = 200V$ |
| $I_{F(AV)} = 50A$ |
| $t_{rr} = 35ns$ |

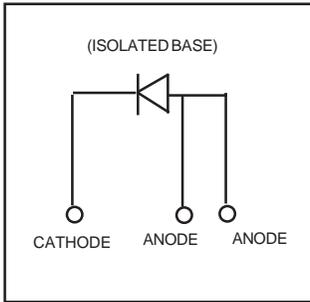
Description

These Ultrafast, soft recovery diodes are optimized to reduce losses and EMI/RFI in high frequency power conditioning systems. An extensive characterization of the recovery behavior for different values of current, temperature and di/dt simplifies the calculations of losses in the operating conditions. The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for power converters, motors drives and other applications where switching losses are significant portion of the total losses.

Absolute Maximum Ratings

| | Parameter | Max. | Units |
|--------------------------|--|-------------|------------|
| V_R | Cathode to Anode Voltage | 200 | V |
| $I_{F(AV)}$ | Continuous Forward Current, ① $T_C = 87^\circ C$ | 50 | A |
| I_{FSM} | Single Pulse Forward Current, ② $T_C = 25^\circ C$ | 450 | |
| $P_D @ T_C = 25^\circ C$ | Maximum Power Dissipation | 167 | W |
| T_J, T_{STG} | Operating Junction and Storage Temperature Range | -55 to +150 | $^\circ C$ |

Note: ① D.C. = 50% rect. wave
 ② 1/2 sine wave, 60 Hz, P.W. = 8.33 ms

| | |
|---|--|
| <p>CASE STYLE</p>  <p>TO-259AA</p> | <p>(ISOLATED BASE)</p>  <p>CATHODE ANODE ANODE</p> |
|---|--|

Electrical Characteristics @ T_J = 25°C (unless otherwise specified)

| | Parameter | Min. | Typ. | Max. | Units | Test Conditions |
|-----------------|---|------|------|------|-------|--|
| V _{BR} | Cathode Anode Breakdown Voltage | 200 | — | — | V | I _R = 100μA |
| V _F | Forward Voltage See Fig. 1 ③ | — | — | 1.34 | V | I _F = 50A, T _J = -55°C ④ |
| | | — | — | 1.28 | | I _F = 50A, T _J = 25°C ④ |
| | | — | — | 1.7 | | I _F = 100A, T _J = 25°C ④ |
| | | — | — | 1.69 | | I _F = 100A, T _J = 125°C ④ |
| I _R | Reverse Leakage Current See Fig. 2 ③ | — | — | 10 | μA | V _R = V _R Rated |
| | | — | — | 100 | μA | V _R = V _R Rated, T _J = 125°C |
| C _T | Junction Capacitance, See Fig. 3 | — | — | 330 | pF | V _R = 200V |
| L _S | Series Inductance | — | 8.7 | — | nH | Measured from anode lead to cathode lead, 6 mm (0.025 in) from package |

Dynamic Recovery Characteristics @ T_J = 25°C (unless otherwise specified)

| | Parameter | Min. | Typ. | Max. | Units | Test Conditions |
|---------------------------|--|------|------|------|-------|--|
| t _{rr} | Reverse Recovery Time | — | — | 35 | ns | I _F = 0.5A, V _R = 30V, di _F /dt = 300A/μs |
| t _{rr1} | Reverse Recovery Time | — | 42 | — | ns | T _J = 25°C See Fig. |
| t _{rr2} | | — | 69 | — | | T _J = 125°C 5 |
| I _R RM1 | Peak Recovery Current | — | 4.4 | — | A | T _J = 25°C See Fig. |
| I _R RM2 | | — | 8.7 | — | | T _J = 125°C 6 |
| Q _{rr1} | Reverse Recovery Charge | — | 108 | — | nC | T _J = 25°C See Fig. |
| Q _{rr2} | | — | 314 | — | | T _J = 125°C 7 |
| di _{(rec)M} /dt1 | Peak Rate of Fall of Recovery Current During t _b | — | 390 | — | A/μs | T _J = 25°C See Fig. |
| di _{(rec)M} /dt2 | | — | 570 | — | | T _J = 125°C 8 |

Thermal - Mechanical Characteristics

| | Parameter | Typ. | Max. | Units |
|-------------------|------------------|------|------|-------|
| R _{thJC} | Junction-to-Case | — | 0.75 | °C/W |
| Wt | Weight | 10.9 | — | g |

Note:

③ Pulse Width < 300μs, Duty Cycle < 2%

④ Pins 2 and 3 externally tied together

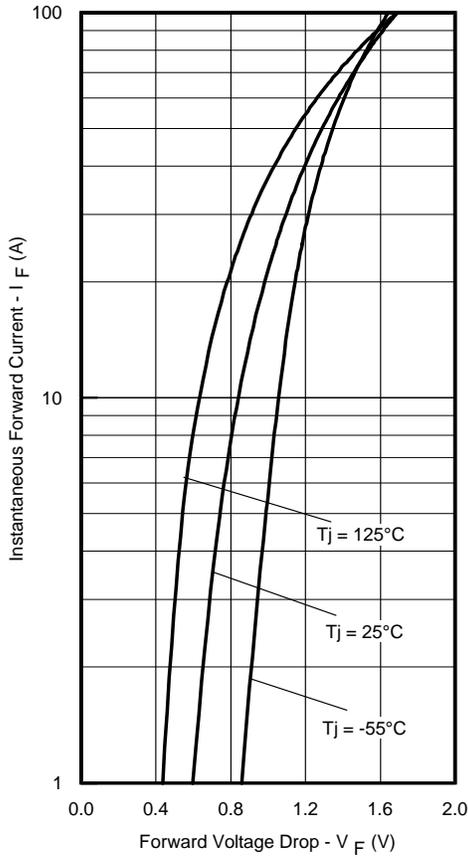


Fig. 1 - Maximum Forward Voltage Drop Vs. Instantaneous Forward Current

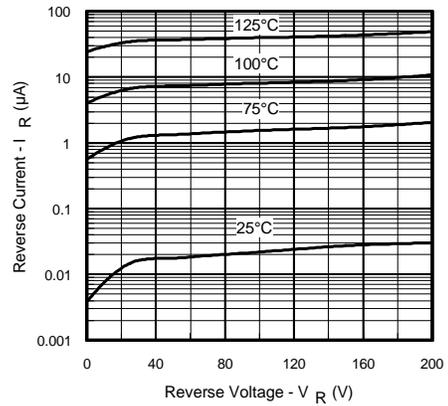


Fig. 2 - Typical Reverse Current Vs. Reverse Voltage

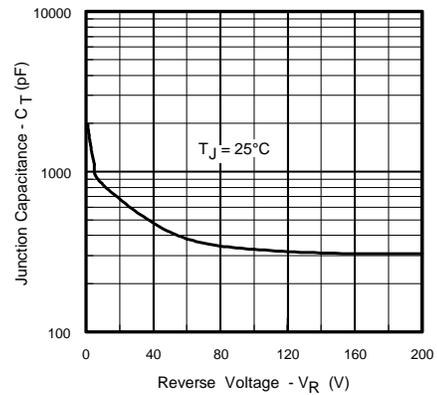


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

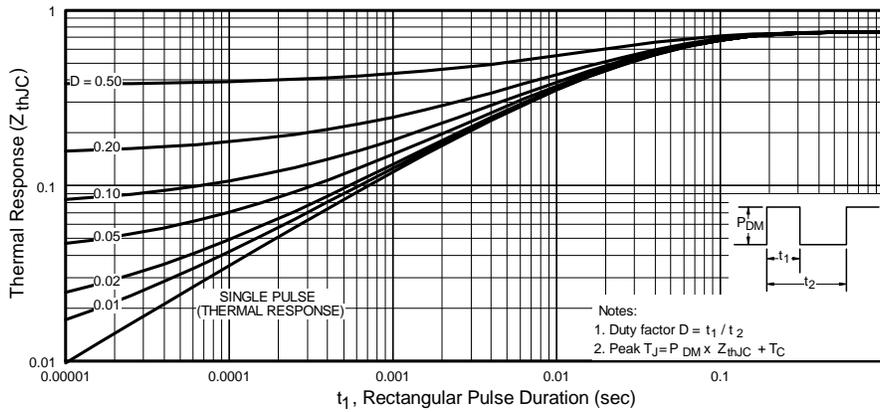


Fig. 4 - Maximum Thermal Impedance Z_{thjC} Characteristics

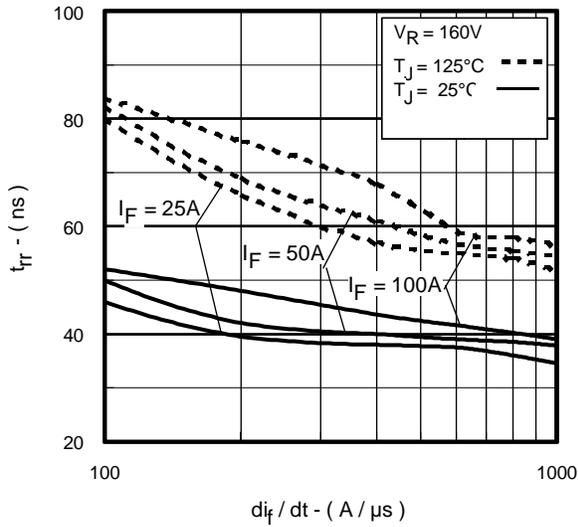


Fig. 5 - Typical Reverse Recovery Vs. di_f/dt ,

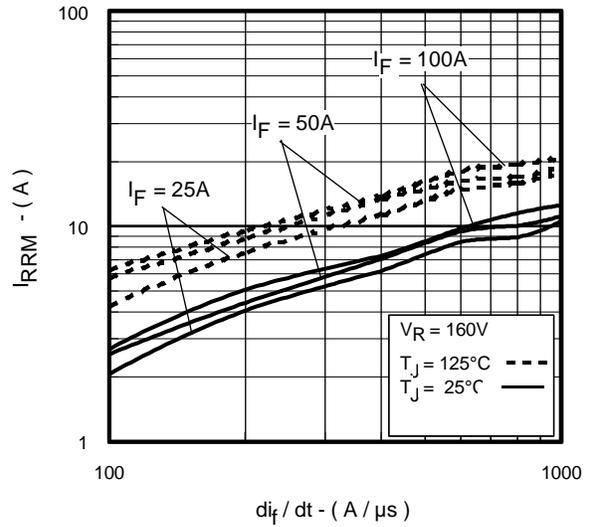


Fig. 6 - Typical Recovery Current Vs. di_f/dt ,

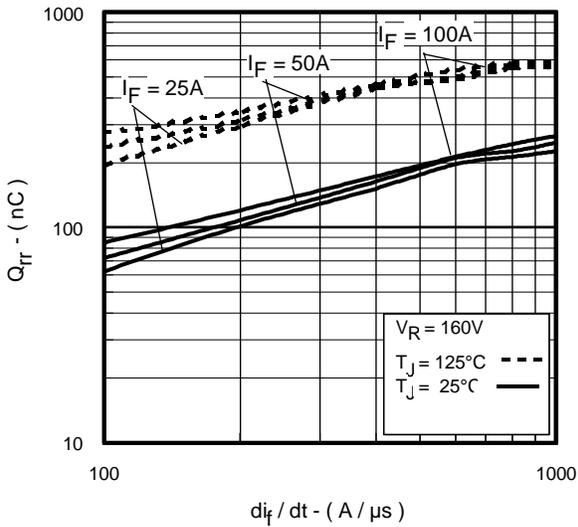


Fig. 7 - Typical Stored Charge Vs. di_f/dt

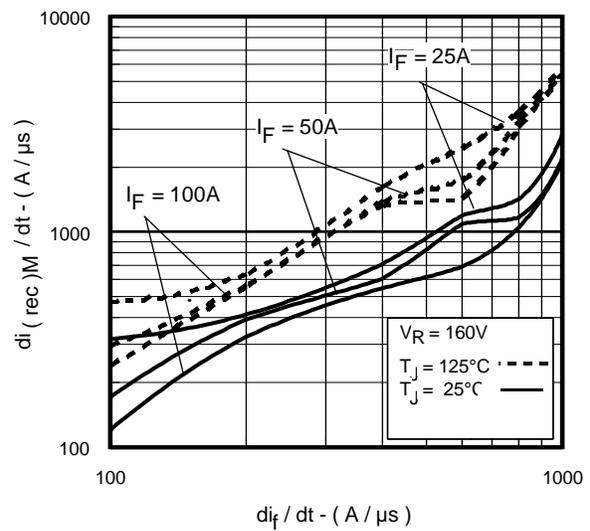
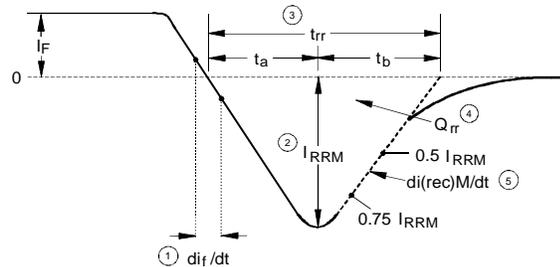
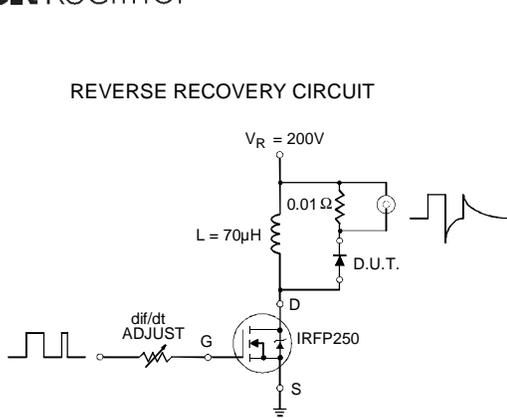


Fig. 8 - Typical $di_{(rec)M}/dt$ Vs. di_f/dt



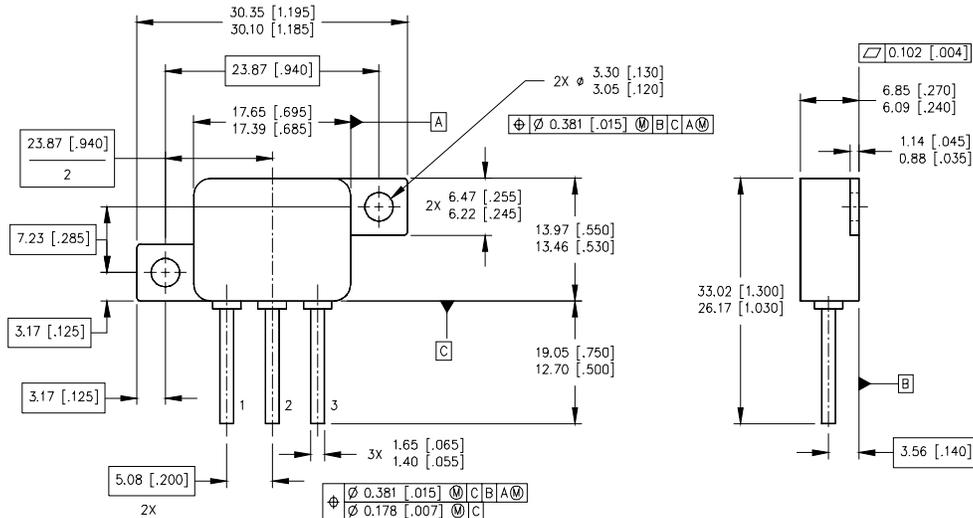
1. di/dt - Rate of change of current through zero crossing
2. I_{RRM} - Peak reverse recovery current
3. t_{rr} - Reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through $0.75 I_{RRM}$ and $0.50 I_{RRM}$ extrapolated to zero current
4. Q_{rr} - Area under curve defined by t_{rr} and I_{RRM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$
5. $di_{(rec)}/dt$ - Peak rate of change of current during t_b portion of t_{rr}

Fig. 9 - Reverse Recovery Parameter Test Circuit

Fig. 10 - Reverse Recovery Waveform and Definitions

Case Outline and Dimensions — TO-259AA



NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME 14.5M-1994.
2. DIMENSIONS ARE SHOWN IN MILLIMETERS [INCHES].
3. CONTROLLING DIMENSION: INCH
4. CONFORMS TO JEDEC OUTLINE TO-259AA.

PIN ASSIGNMENTS

- 1 = CATHODE
- 2 = ANODE
- 3 = ANODE